

10 Watt MMDS Packaged Amplifier

TGA2923-SG



Key Features

- 3.5 GHz Application Frequency Range
- 9 dB Nominal Gain
- 10 Watt Nominal Psat
- 2.5% EVM at 30 dBm output power
- IMD3 -45 dBc @ 28 dBm SCL, Typical
- Bias Conditions: 8 V @ 1.2 A (Quiescent)
- 0.5 μ m HFET Technology
- 2 lead Cu-alloy base and internally partially matched package

Primary Applications

- 802.16 Broadband Wireless
- WiMAX

Product Description

The TGA2923-SG HPA provides 9 dB of gain, 10 W of output power at 3.5 GHz and 2.5% EVM at 30 dBm output power for OFDM 64 QMA. The device is ideally suited for high linearity, high power wireless data applications such as 802.16 and WiMAX. The package has a high thermal conductivity copper alloy base. Internal partial matching simplifies system board layout by requiring a minimum of external components. The device can be tuned to 3.3 - 3.8GHz range in 200 MHz bandwidth. 2 object components (C4 & C5) can be tuned for bandwidth.

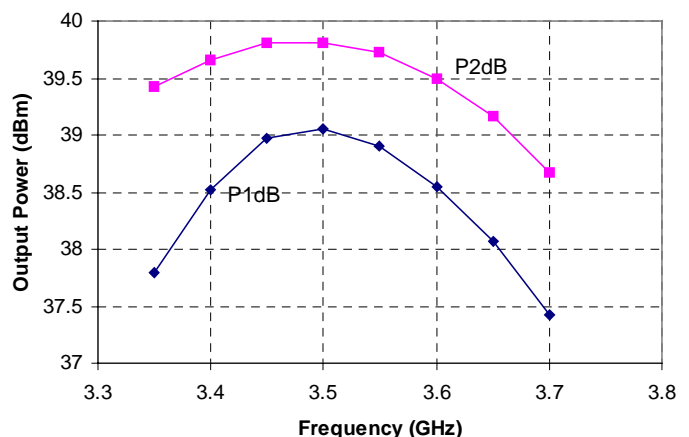
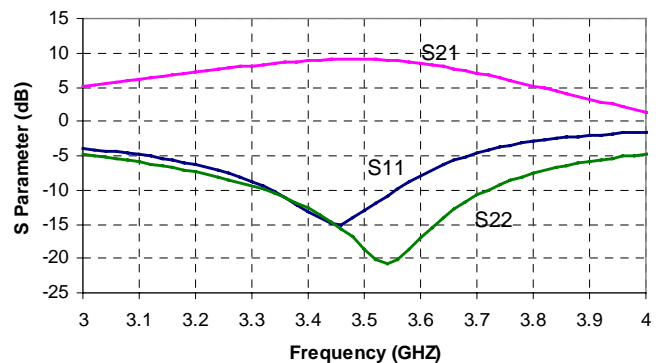
Lead-Free & RoHS compliant.

Evaluation Boards are available.

Fixture Measured Performance

Bias Conditions: $V_d = 8$ V, $I_{dq} = 1.2$ A

Performance data taken in a 3.5 GHz application circuit



Note: This device is early in the characterization process prior to finalizing all electrical specifications. Specifications are subject to change without notice.

TABLE I
MAXIMUM RATINGS 1/

Symbol	Parameter	Value	Notes
V _d	Drain Supply Voltage	10 V	<u>2/</u>
V _g	Gate Supply Voltage Range	0 V to -5 V	
I _d	Drain Supply Current	4 A	<u>2/</u>
I _g	Gate Current	39 mA	
P _{IN}	Input Continuous Wave Power	36 dBm	<u>2/</u>
P _D	Power Dissipation	11.2 W	<u>2/</u> , <u>3/</u>
T _{CH}	Operating Channel Temperature	175 °C	4/
T _M	Mounting Temperature (30 Seconds)	260 °C	
T _{STG}	Storage Temperature	-65 to 150 °C	

- 1/ These ratings represent the maximum operable values for this device.
- 2/ Combinations of supply voltage, supply current, input power, and output power shall not exceed P_D.
- 3/ When operated at this bias condition with a base plate temperature of 85 °C, the MTTF life is 2 E+8 hours.
- 4/ Junction operating temperature will directly affect the device median time to failure (T_M). For maximum life, it is recommended that junction temperatures be maintained at the lowest possible levels.

TABLE II
RF CHARACTERIZATION TABLE
($T_A = 25^\circ\text{C}$, Nominal)
($V_d = 8\text{ V}$, $I_{dq} = 1.2\text{ A}$)

SYMBOL	PARAMETER	TEST CONDITION	TYPICAL	UNITS
Gain	Small Signal Gain	f = 3.5 GHz	9	dB
IRL	Input Return Loss	f = 3.5 GHz	12	dB
ORL	Output Return Loss	f = 3.5 GHz	15	dB
Psat	Saturated Output Power	f = 3.5 GHz	40	dBm

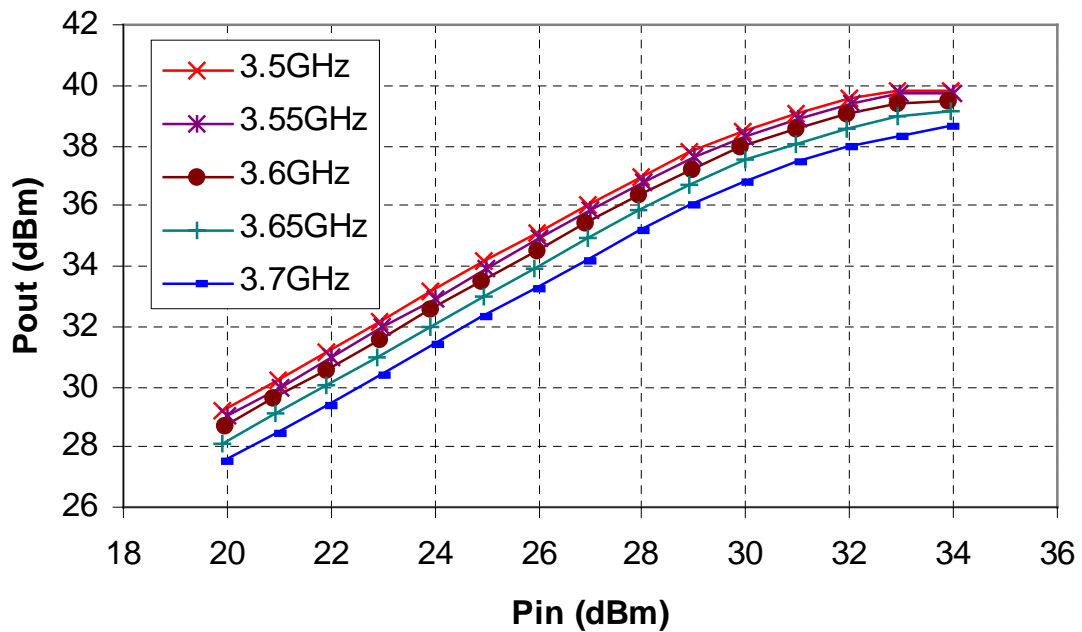
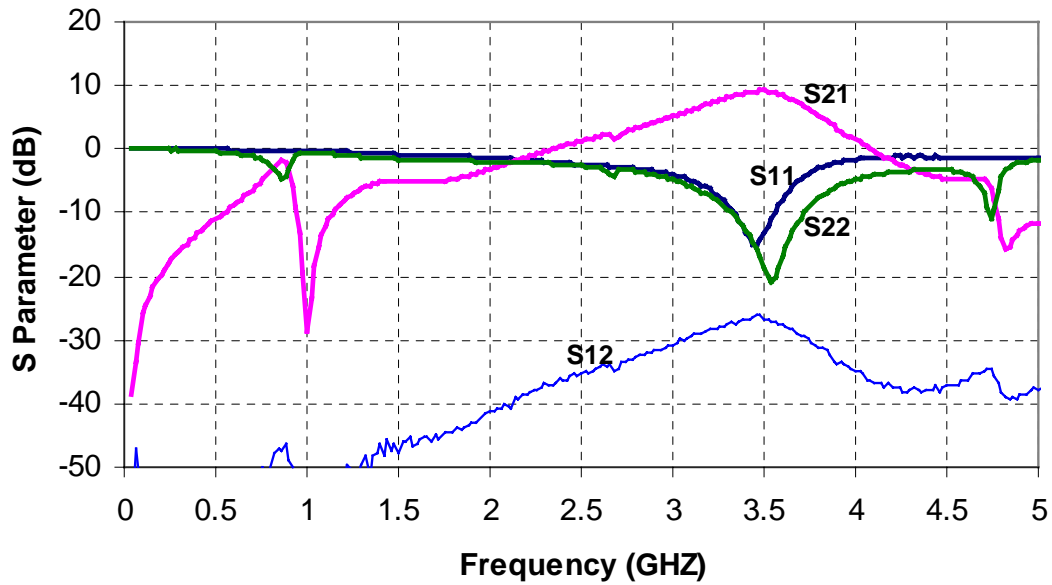
TABLE III
THERMAL INFORMATION

Parameter	Test Conditions	T_{CH} ($^\circ\text{C}$)	$R_{\theta JC}$ ($^\circ\text{C/W}$)	T_M (HRS)
$R_{\theta JC}$ Thermal Resistance (channel to backside of package)	$V_d = 8\text{ V}$ $I_D = 1.2\text{ A}$ $P_{diss} = 9.6\text{ W}$	162	8	7.7 E+8

Note: Package backside was soldered to carrier at 85°C baseplate temperature. At saturated output power, the DC power consumption is 20W with 10W RF power delivered to the load and 10W dissipated. Adding the 1W RF input power results in 11W total power dissipation and a maximum channel temperature of 173°C at 85°C baseplate temperature.

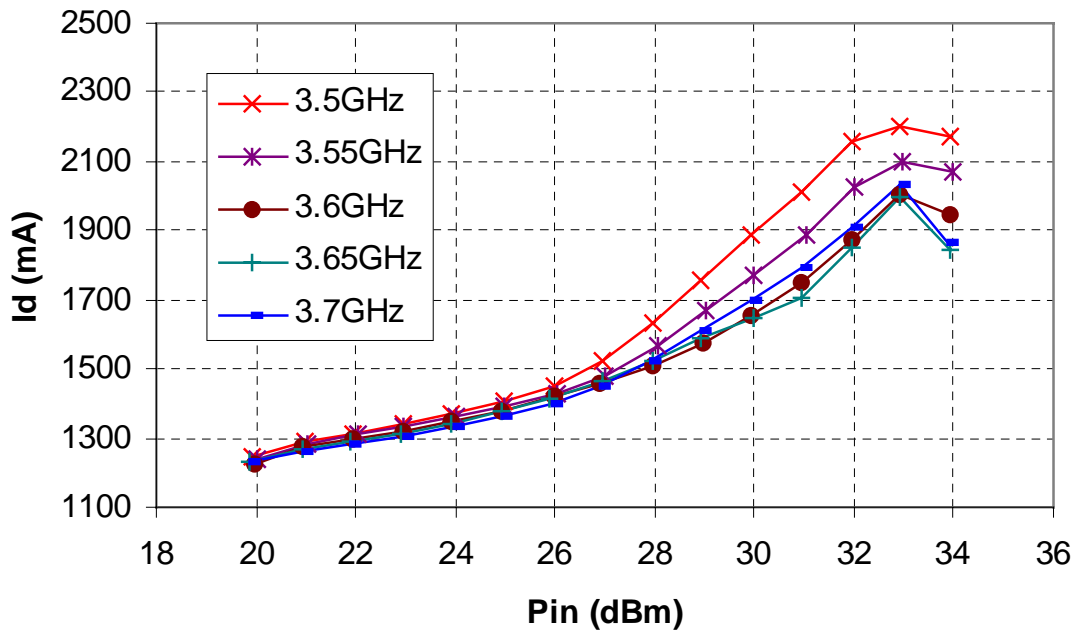
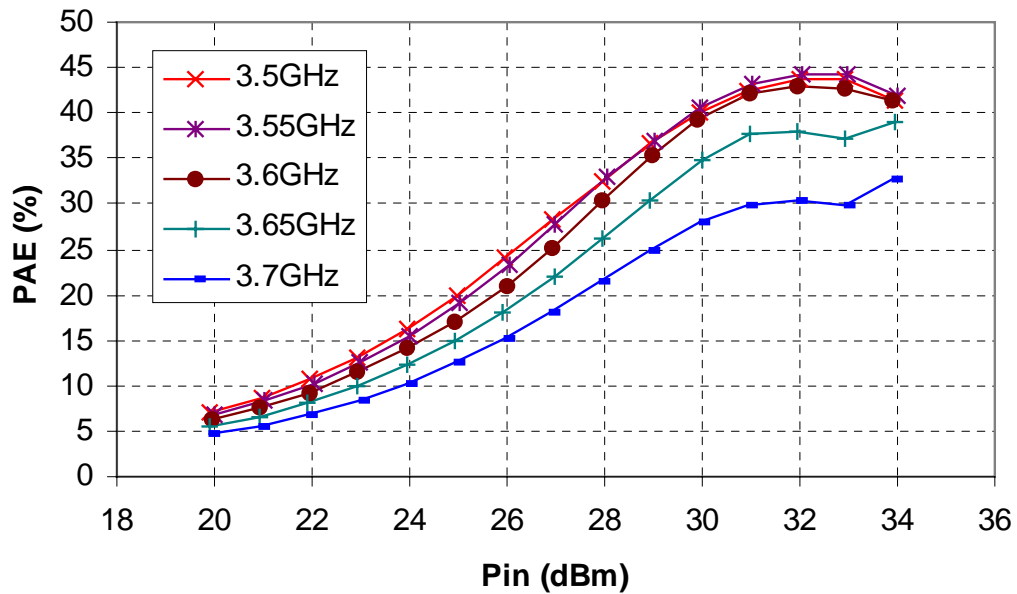
Measured Fixtured Data
Application Circuit tuned to 3.5 GHz

Bias Conditions: $V_d = 8\text{ V}$, $I_{dq} = 1.2\text{ A}$



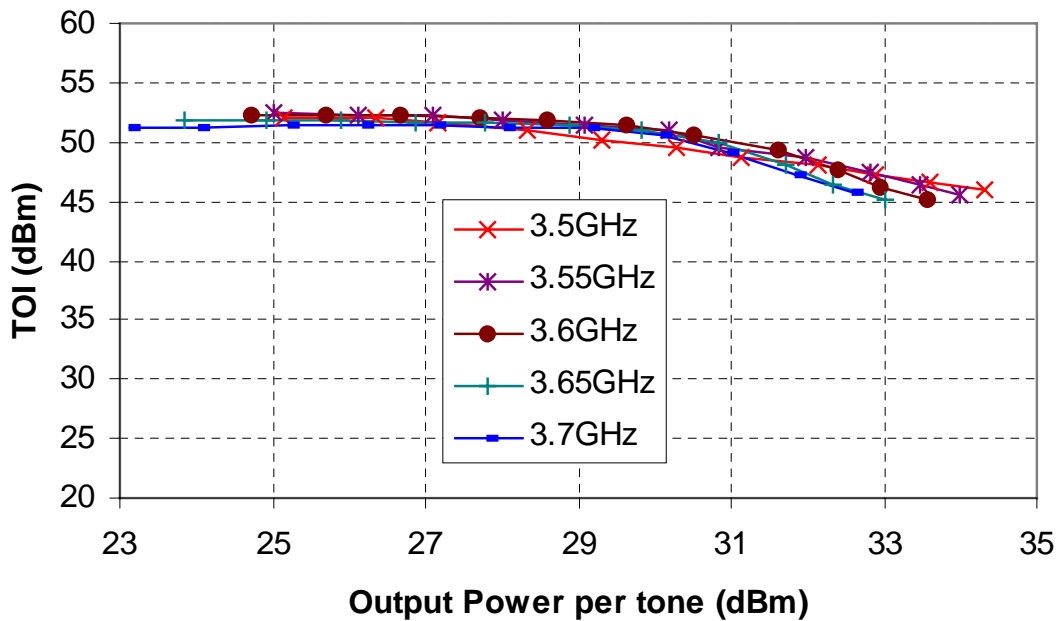
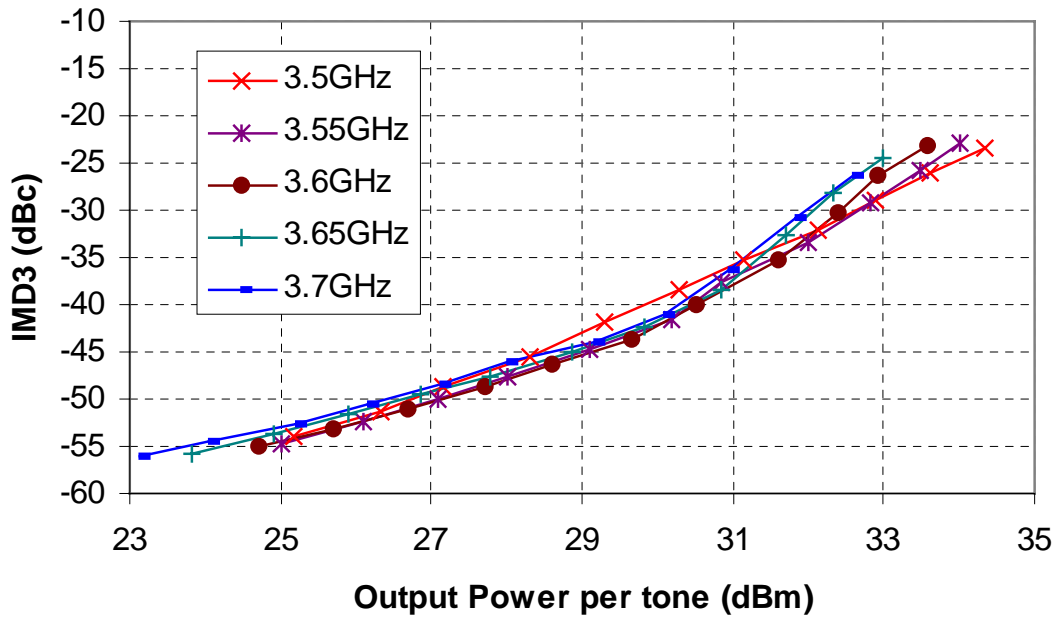
**Measured Fixtured Data
Application Circuit tuned to 3.5 GHz**

Bias Conditions: $V_d = 8\text{ V}$, $I_{dQ} = 1.2\text{ A}$



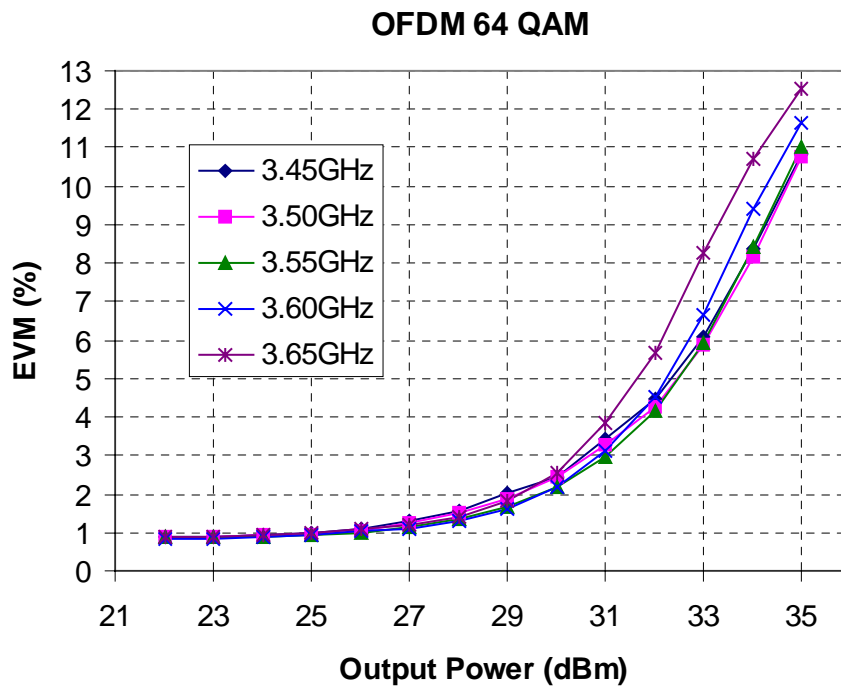
**Measured Fixtured Data
Application Circuit tuned to 3.5 GHz**

Bias Conditions: $V_d = 8\text{ V}$, $I_{dq} = 1.2\text{ A}$

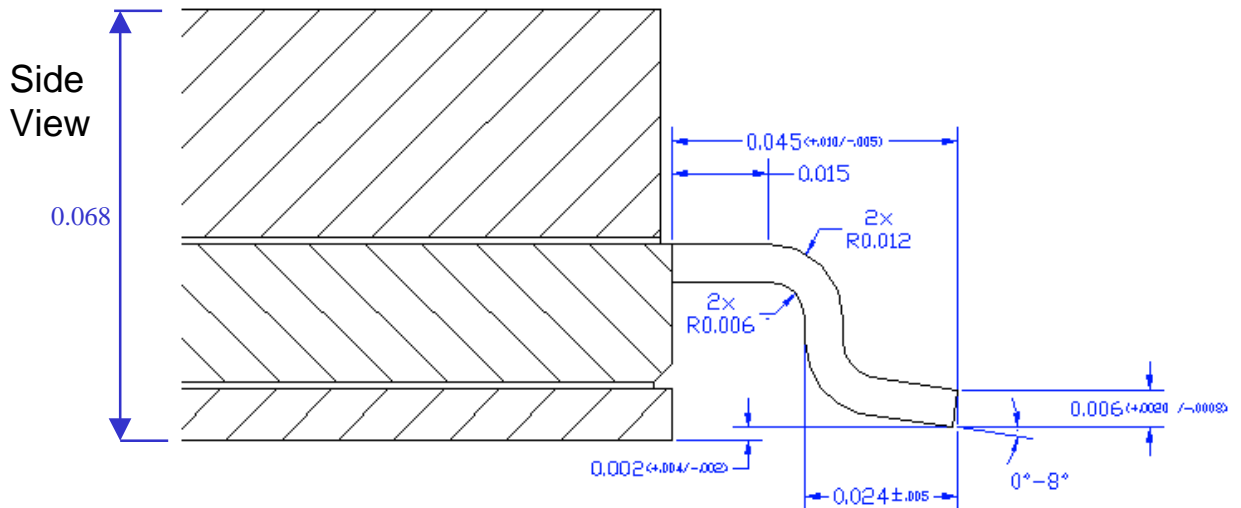
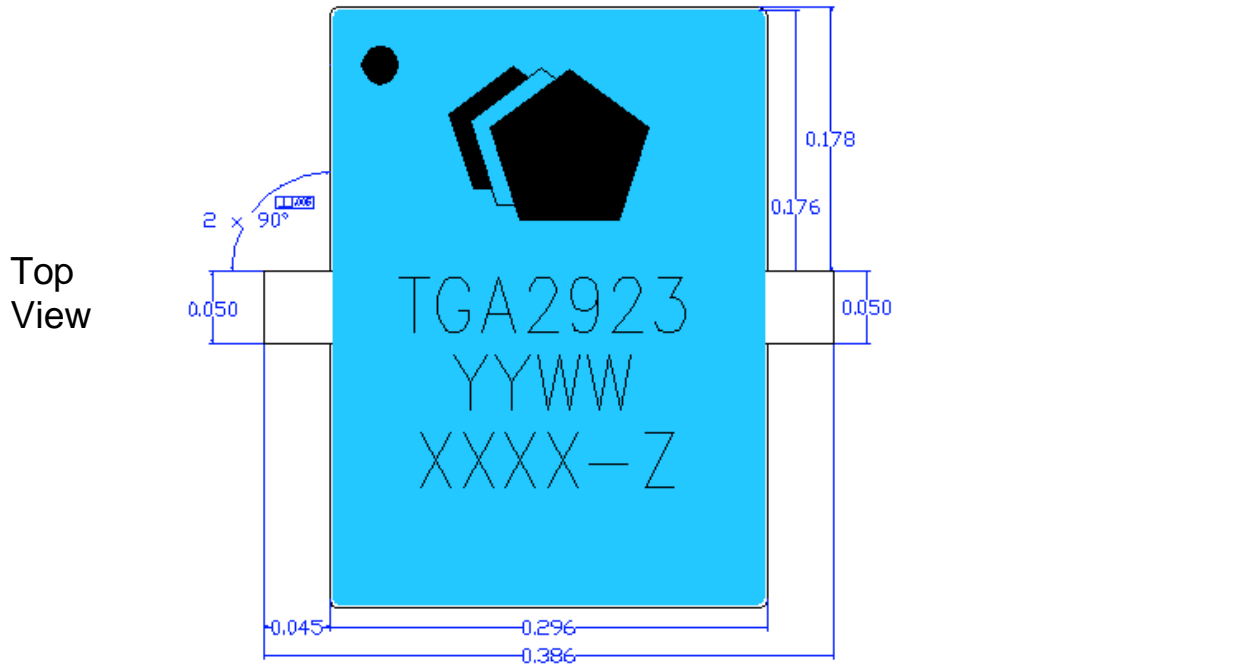


Measured Fixtured Data
Application Circuit tuned to 3.5 GHz

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Mechanical Drawing TGA2923 - SG

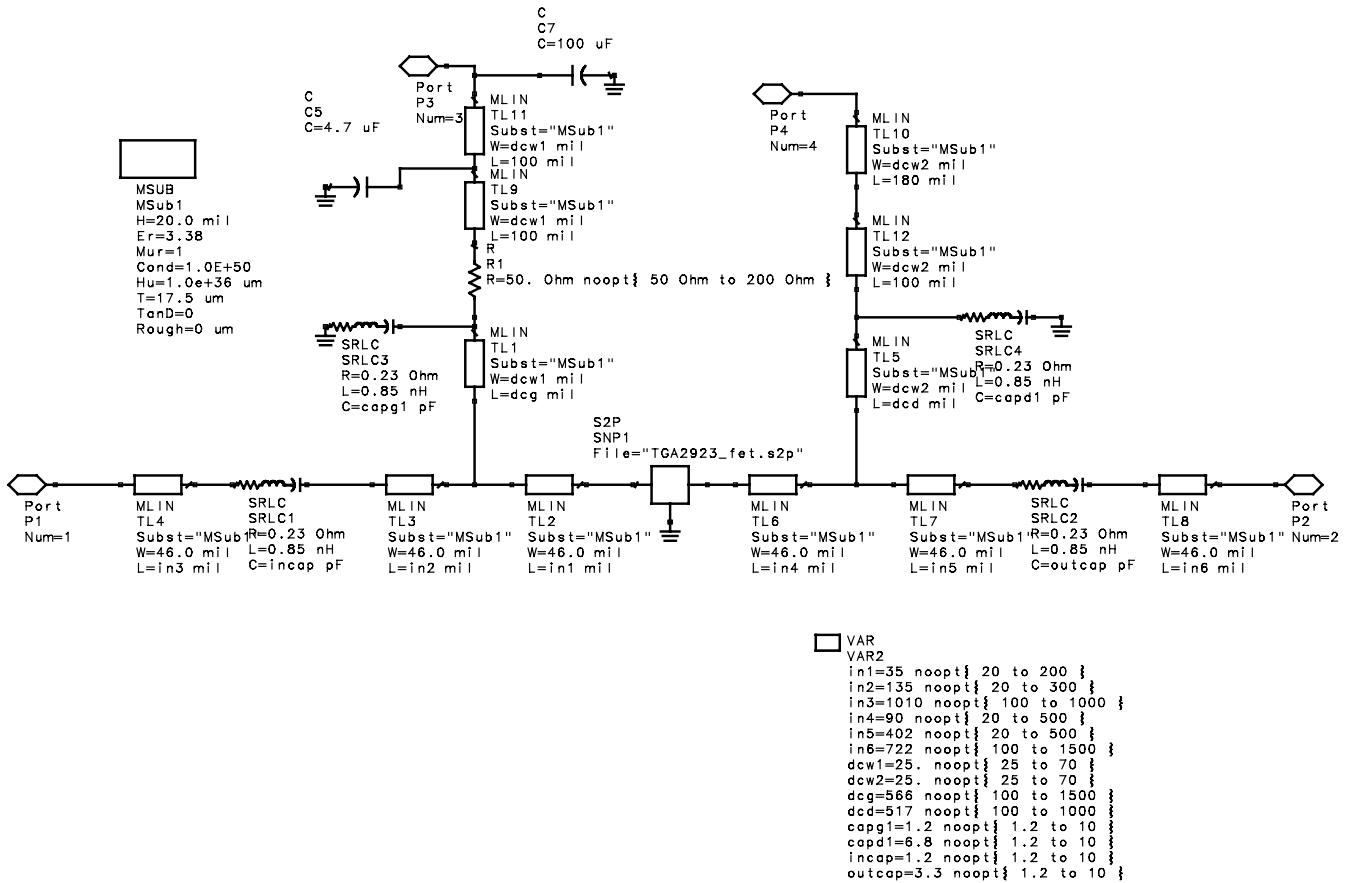


Note: All dimensions are in inches

Bias Procedure

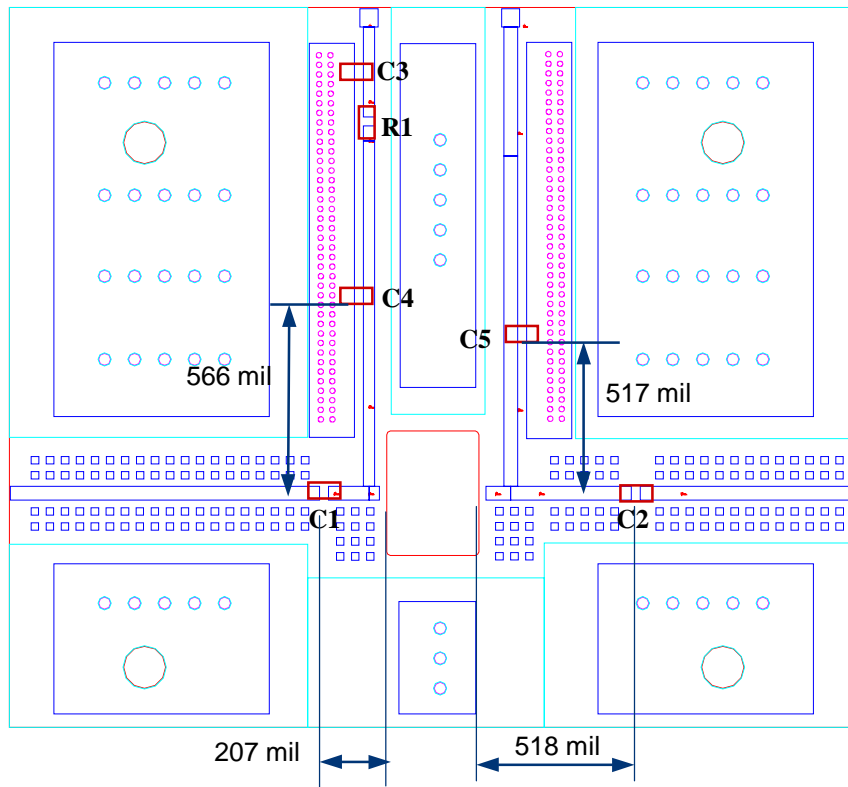
1. Ensure no RF power is applied to the device.
2. Pinch off device by setting V_g to $-3V$.
3. Increase V_d to 8.0V while monitoring drain current.
4. Increase V_g until drain current reaches 1.2A
5. Apply RF power.

3.5 GHz Application Circuit Schematic



PCB is 20 mil thick Rogers 4003 substrate

Typical Evaluation Board Layout *



*The layout is a general purpose drawing that needs to be tuned for the specific application. PCB is RO4003 20 mil thickness, 0.5 oz standard copper cladding, with $\epsilon_r = 3.38$.

External Component Listing

Part Type	Reference	Description
Capacitor	C1	AVX 06035J5R6BBT, 1.2 pF
Capacitor	C2	AVX 06035J5R6BBT, 3.3pF
Capacitor	C3	4.7uF
Capacitor	C4	AVX 06035J8R2BBT, 1.2pF
Capacitor	C5	AVX 06035J8R2BBT, 6.8pF
Resistor	R1	0805, 50 Ω

Recommended Surface Mount Package Assembly

Proper ESD precautions must be followed while handling packages.

Clean the board with acetone. Rinse with alcohol. Allow the circuit to fully dry.

TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.

Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.

Clean the assembly with alcohol.

Typical Solder Reflow Profiles

Reflow Profile	SnPb	Pb Free
Ramp-up Rate	3 °C/sec	3 °C/sec
Activation Time and Temperature	60 – 120 sec @ 140 – 160 °C	60 – 180 sec @ 150 – 200 °C
Time above Melting Point	60 – 150 sec	60 – 150 sec
Max Peak Temperature	240 °C	260 °C
Time within 5 °C of Peak Temperature	10 – 20 sec	10 – 20 sec
Ramp-down Rate	4 – 6 °C/sec	4 – 6 °C/sec

Ordering Information

Part	Package Style
TGA2923-SG	Gull Wing Leads